



IR Emitter and Detector Product Data Sheet

HSDL-4260

Spec No.: DS50-2008-0025

Effective Date: 06/18/2013

Revision: B

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

FEATURES

* High power AlGaAs LED technology

* T-1 3/4 Package

application

* 875 nm Wavelength

* High speed: 40ns Rise times

* Low Forward Voltage

* Applications

Industrial Infrared Equipments and

Portable Infrared Instruments

Consumer Electronics

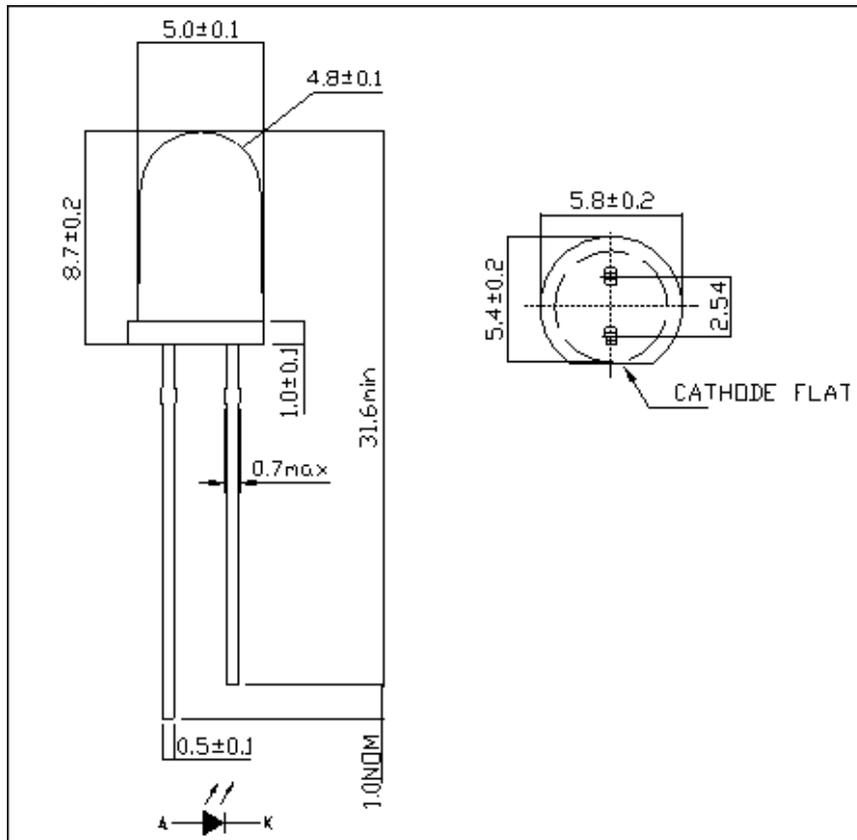
(Optical mouse, Infrared Remote Controllers ect)

High Speed Infrared Communications

(IR LANs , IR Moldens , IR Dongles , etc)



PACKAGE DIMENSIONS



NOTES:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25mm(.010") unless otherwise noted.
3. Protruded resin under flange is 1.5mm(.059") max.
4. Lead spacing is measured where the leads emerge from the package.
5. Specifications are subject to change without notice.



LITE-ON TECHNOLOGY CORPORATION.

Property of Lite-On Only

BNS-OD-C131/A4

ABSOLUTE MAXIMUM RATINGS AT TA=25°C

PARAMETER	Symbol	MIN	MAX	UNIT	Reference
Forward Current	I _{FDC}		100	mA	[1]
Peak Forward Current	I _{FPK}		500	mA	Fig 3 Duty Factor=20% Pulse Width=100us
Power Dissipation	P _{DISS}		230	mW	
Reverse Voltage	V _R	4		V	IR=100uA
Storage Temperature	T _S	-40	100	°C	
LED Junction Temperature	T _J		110	°C	
Lead Soldering Temperature [1.6mm(.063") From Body]			260 for 5 seconds	°C	

Notes:

1. Derate as shown in Figure 6.

Recommended Operating Conditions

PARAMETER	Symbol	MIN	MAX	UNIT	Reference
Operating Temperature	T _O	-40	85	°C	

ELECTRICAL CHARACTERISTICS AT 25°C

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	Reference
Forward Voltage	V_F		1.4	1.9	V	$I_{FDC} = 20\text{mA}$	Fig.2
			1.7	2.3	V	$I_{FDC} = 100\text{mA}$	
Forward Voltage Temperature Coefficient	$\Delta V/\Delta T$		-1.3		mV/°C	$I_{FDC} = 100\text{mA}$	Fig.4
Series Resistance	R_S		4		Ohms	$I_{FDC} = 100\text{mA}$	
Diode Capacitance	C_O		70		pF	0 V, 1 MHz	
Reverse Voltage	V_R	2	20		V	$I_R = 100\ \mu\text{A}$	
Thermal Resistance, Junction to Pin	$R\theta_{JA}$		300		°C/W		

OPTICAL CHARACTERISTICS AT TA=25°C

PARAMETER	Symbol	MIN.	TYP.	MAX.	UNIT	Test condition	Reference
Radiant On-Axis Intensity	I_E	150	200		Mw/Sr	$I_{FDC} = 100\text{mA}$	Fig.5
Radiant On-Axis Intensity Temperature Coefficient	$\Delta I_E / \Delta T$	-	-0.36	-	%/°C	$I_{FDC} = 100\text{mA}$	
Viewing Angle	$2\theta_{1/2}$	-	15	-	deg	$I_{FDC} = 20\text{mA}$	Fig.7
Peak Wavelength	λ_{pk}	-	875	-	nm		Fig.1
Peak Wavelength Temperature Coefficient	$\Delta \lambda / \Delta T$	-	0.2	-	nm/°C	$I_{FDC} = 100\text{mA}$	
Spectral Width-at FWHM	$\Delta \lambda$		45	-	nm	$I_{FDC} = 20\text{mA}$	Fig.1
Optical Rise and all Times, 10%-90%	T_r / T_f		15	-	ns	$I_{FDC} = 500\text{ mA}$ Duty Ratio=20% Pulse Width=100ns	

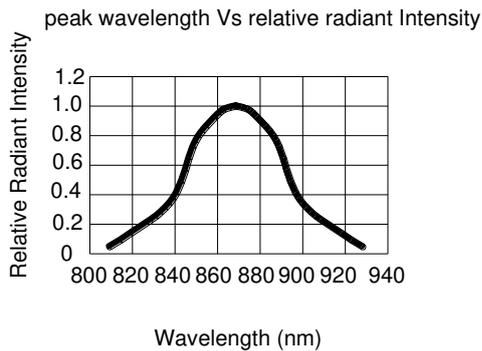


FIG.1 Relative Radiant Intensity VS Wavelength

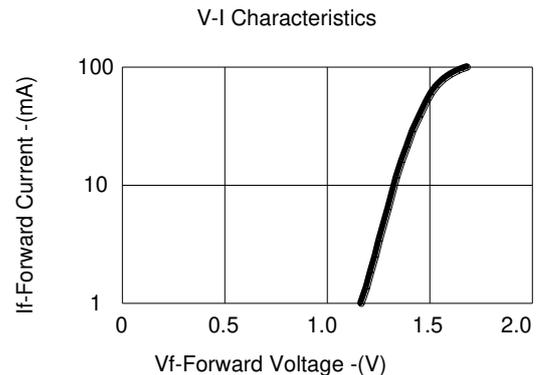


FIG.2 DC Forward Current VS. Forward Voltage

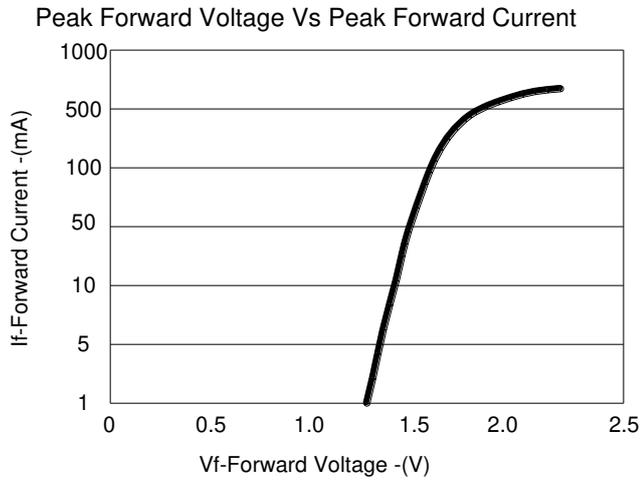


FIG.3 Peak Forward Current VS. Forward Voltage
Forward Current Vs Relative Radiant Intensity

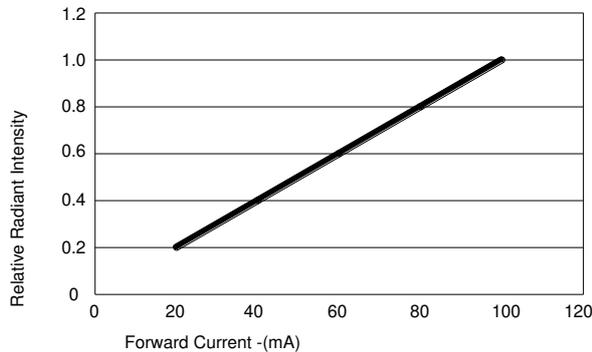


FIG.5 Relative Radiant Intensity vs DC Forward Current

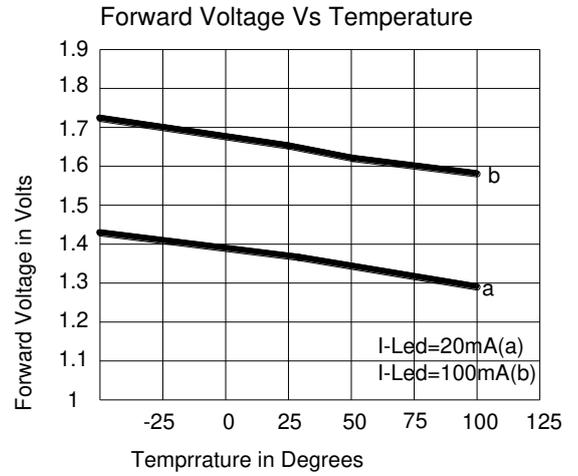


FIG.4 Forward Voltage VS. Ambient Temperature

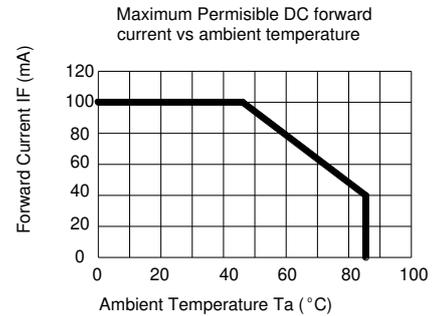
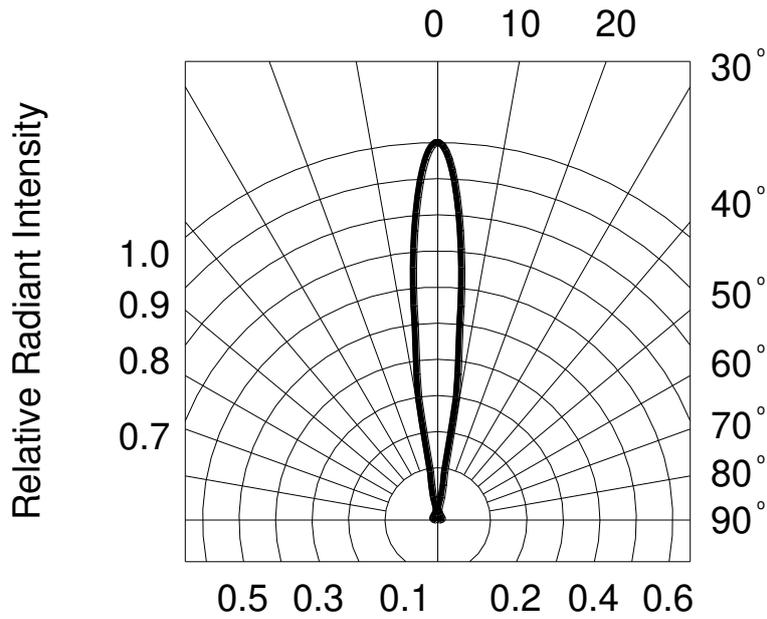


FIG.6 DC FORWARD CURRENT VS. AMBIENT TEMPERATURE DERATED (Based on T_{JMAX}=110°C)

**FIG.7 RADIATION DIAGRAM**